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## \*BIBDATASHEET\*

CONFIRMATION NO. 7014

Bib Data Sheet

SERIAL NUMBER 09/741,195	FILING DATE 12/21/2000  RULE	CLASS 257	GROUP ART UNIT 2811	ATTORNEY DOCKET NO. 040373/0300
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APPLICANTS

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\*\* CONTINUING DATA \*\*\*\*\*

\*\* FOREIGN APPLICATIONS \*\*\*\*\*  
 JAPAN 11-367831 12/24/1999 *qv*

IF REQUIRED, FOREIGN FILING LICENSE GRANTED  
 \*\* 02/28/2001

Foreign Priority claimed 35 USC 119 (a-d) conditions met Verified and Acknowledged	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance <i>Lawyer</i> <i>qv</i> Examiner's Signature Initials	STATE OR COUNTRY JAPAN	SHEETS DRAWING 47	TOTAL CLAIMS 24	INDEPENDENT CLAIMS 4
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 22428  
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TITLE  
 Semiconductor device with high- and low-density regions of transistor elements on single semiconductor substrate, and method of manufacturing such semiconductor device

FILING FEE  RECEIVED 1006	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees ( Filing ) <input type="checkbox"/> 1.17 Fees ( Processing Ext. of time ) <input type="checkbox"/> 1.18 Fees ( Issue )
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